

## Features

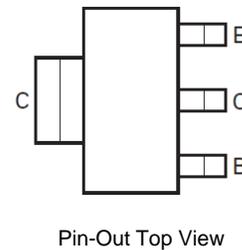
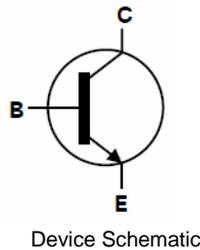
- $BV_{CEO} > 60V$
- $I_C = 6A$  Continuous Collector Current
- $I_{CM} = 20A$  Peak Pulse Current
- Low Saturation Voltage  $V_{CE(SAT)} < 60mV$  Max @ 1A
- $R_{SAT} = 35m\Omega$  @  $I_C = 6A$  for Low Equivalent On-Resistance
- $h_{FE}$  Specified up to 10A for High Gain Hold Up
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

## Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic. "Green" Molding Compound; UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads; Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)

## Applications

- Emergency Lighting Circuits
- Motor Driving (Including DC Fans)
- Solenoid, Relay and Actuator Drivers
- DC Modules
- Backlight Inverters

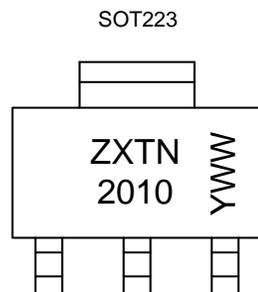


## Ordering Information (Note 4)

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTN2010GTA	ZXTN2010	7	12	1,000

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
  2. See [http://www.diodes.com/quality/lead\\_free.html](http://www.diodes.com/quality/lead_free.html) for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
  3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
  4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

## Marking Information



ZXTN 2010 = Product Type Marking Code  
 YWW = Date Code Marking  
 Y or  $\bar{Y}$  = Last Digit of Year (ex: 5= 2015)  
 WW or  $\bar{W}W$  = Week Code (01-53)

**Absolute Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	150	V
Collector-Emitter Voltage	V <sub>CEO</sub>	60	V
Emitter-Base Voltage	V <sub>EBO</sub>	7	V
Continuous Collector Current	I <sub>C</sub>	6	A
Peak Pulse Current	I <sub>CM</sub>	20	A

**Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

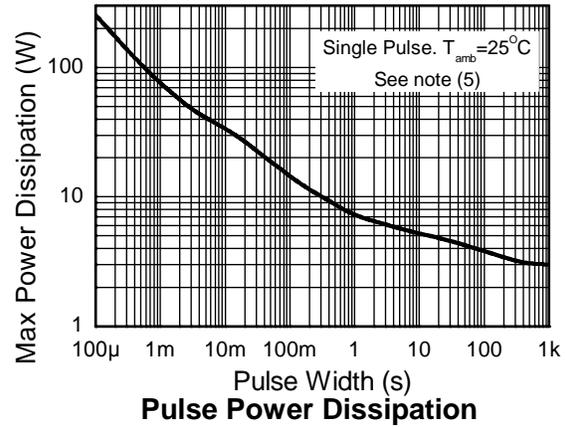
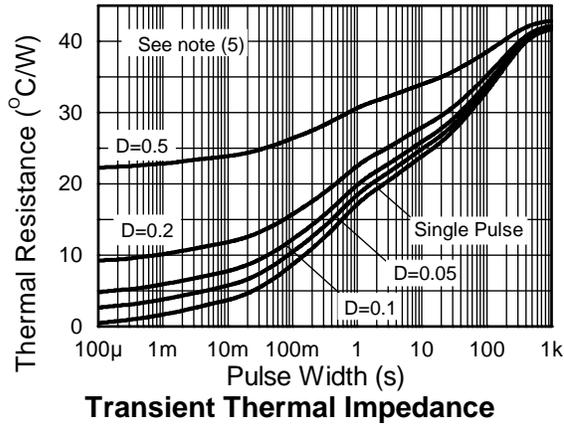
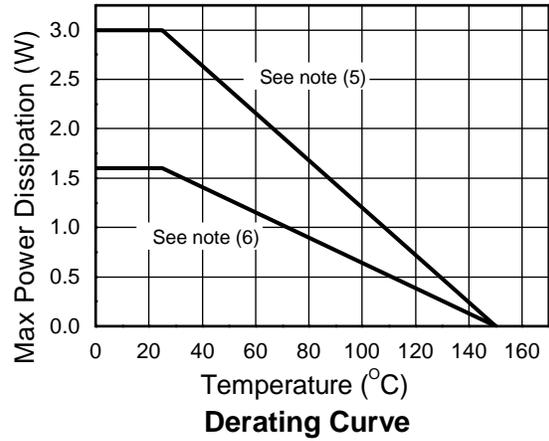
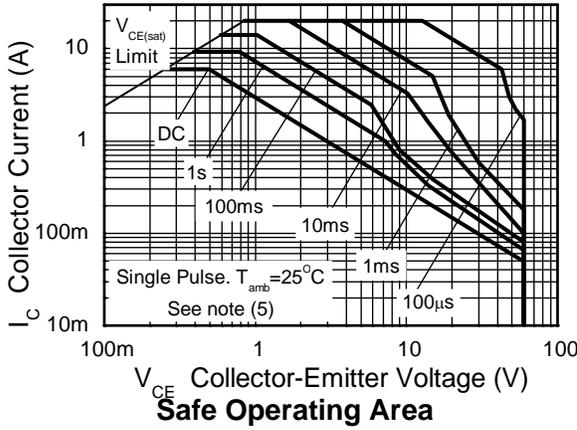
Characteristic	Symbol	Value	Unit
Power Dissipation	P <sub>D</sub>	3.0	W
		24	
Linear Derating Factor		1.6	mW/°C
		12.8	
Thermal Resistance, Junction to Ambient	R <sub>θJA</sub> (Note 5)	42	°C/W
	R <sub>θJA</sub> (Note 6)	78	
Thermal Resistance, Junction to Lead	R <sub>θJL</sub> (Note 7)	8.8	
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

**ESD Ratings** (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	C

- Notes:
5. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in steady-state.
  6. Same as Note 5, except the device is mounted on 25mm x 25mm 1oz copper.
  7. Thermal resistance from junction to solder-point (at the end of the collector lead).
  8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

**Thermal Characteristics and Derating Information**

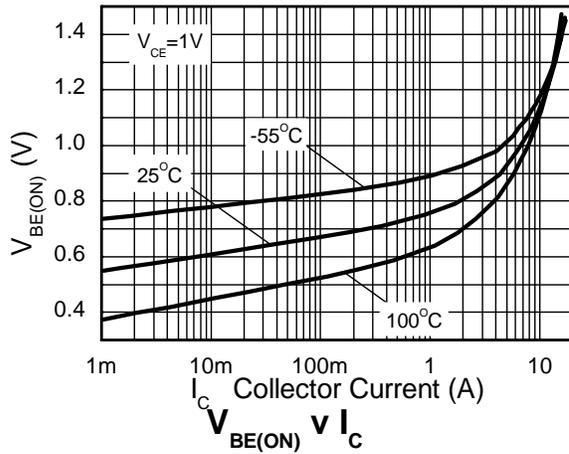
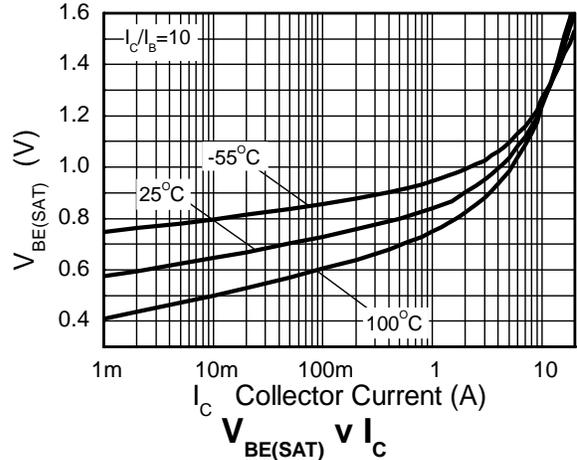
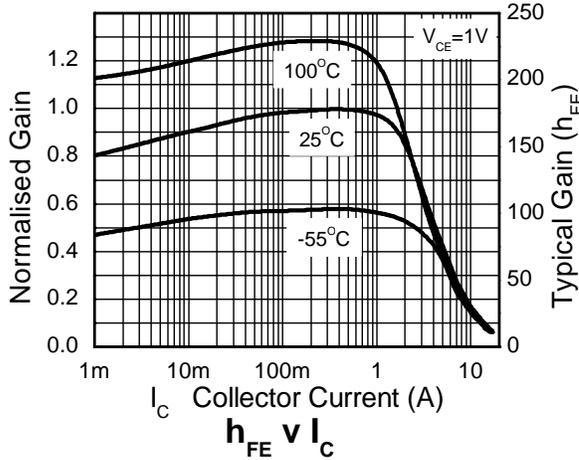
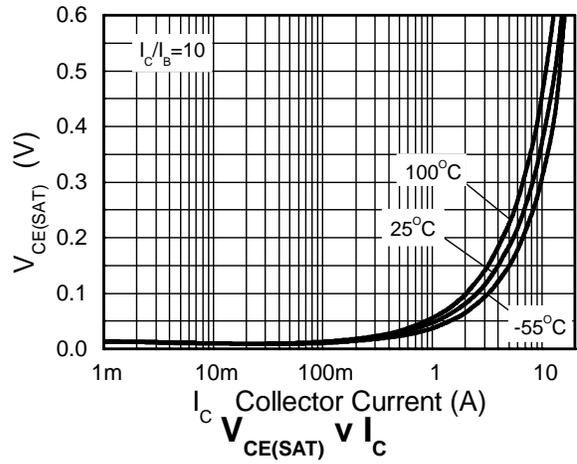
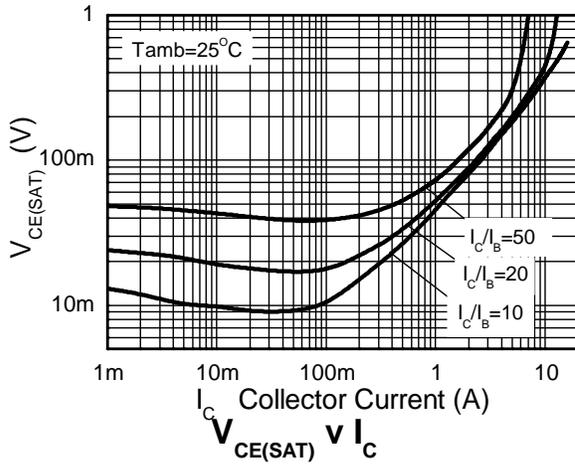


**Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_{CBO}$	150	190	—	V	$I_C = 100\mu\text{A}$
Collector-Emitter Breakdown Voltage	$BV_{CER}$	150	190	—	V	$I_C = 1\mu\text{A}$ , $R_B \leq 1\text{k}\Omega$
Collector-Emitter Breakdown Voltage (Note 9)	$BV_{CEO}$	60	80	—	V	$I_C = 10\text{mA}$
Emitter-Base Breakdown Voltage	$BV_{EBO}$	7	8.1	—	V	$I_E = 100\mu\text{A}$
Collector Cut-Off Current	$I_{CBO}$	—	—	50 0.5	nA $\mu\text{A}$	$V_{CB} = 120\text{V}$ $V_{CB} = 120\text{V}$ , $T_A = +100^\circ\text{C}$
Collector Cut-Off Current	$I_{CER}$ $R \leq 1\text{k}\Omega$	—	—	100 0.5	nA $\mu\text{A}$	$V_{CB} = 120\text{V}$ $V_{CB} = 120\text{V}$ , $T_A = +100^\circ\text{C}$
Emitter Cut-Off Current	$I_{EBO}$	—	—	10	nA	$V_{EB} = 6\text{V}$
Collector-Emitter Saturation Voltage (Note 9)	$V_{CE(sat)}$	—	20 45 50 100 210	30 60 70 135 260	mV	$I_C = 0.1\text{A}$ , $I_B = 5\text{mA}$ $I_C = 1\text{A}$ , $I_B = 100\text{mA}$ $I_C = 1\text{A}$ , $I_B = 50\text{mA}$ $I_C = 2\text{A}$ , $I_B = 50\text{mA}$ $I_C = 6\text{A}$ , $I_B = 300\text{mA}$
Base-Emitter Saturation Voltage (Note 9)	$V_{BE(sat)}$	—	1	1.1	V	$I_C = 6\text{A}$ , $I_B = 300\text{mA}$
Base-Emitter Turn-on Voltage (Note 9)	$V_{BE(on)}$	—	0.94	1.05	V	$I_C = 6\text{A}$ , $V_{CE} = 1\text{V}$
DC Current Gain (Note 9)	$h_{FE}$	100 100 55 20	200 200 105 40	— 300 — —		$I_C = 10\text{mA}$ , $V_{CE} = 1\text{V}$ $I_C = 2\text{A}$ , $V_{CE} = 1\text{V}$ $I_C = 5\text{A}$ , $V_{CE} = 1\text{V}$ $I_C = 10\text{A}$ , $V_{CE} = 1\text{V}$
Transition Frequency	$f_T$	—	130	—	MHz	$V_{CE} = 10\text{V}$ , $I_C = 100\text{mA}$ , $f = 50\text{MHz}$
Output Capacitance (Note 9)	$C_{obo}$	—	31	—	pF	$V_{CB} = 10\text{V}$ , $f = 1\text{MHz}$
Switching Times	$t_{ON}$	—	42	—	ns	$V_{CC} = 10\text{V}$ , $I_C = 1\text{A}$ , $I_{B1} = -I_{B2} = 100\text{mA}$
	$t_{OFF}$	—	760	—		

Note: 9. Measured under pulsed conditions. Pulse width  $\leq 300\mu\text{s}$ . Duty cycle  $\leq 2\%$ .

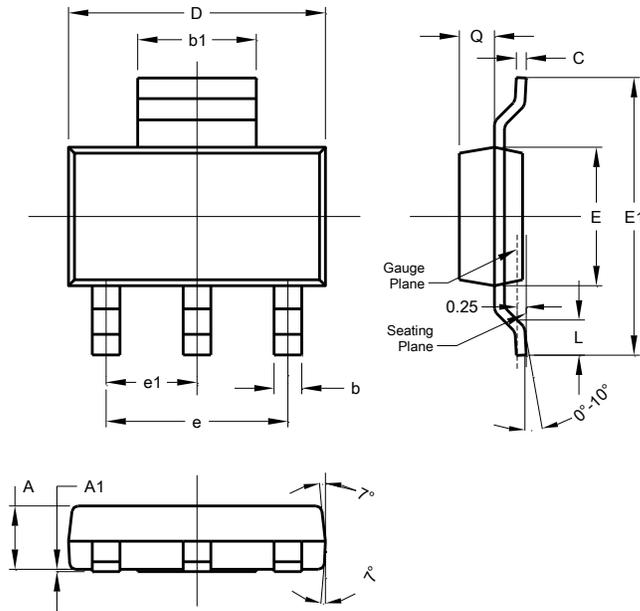
**Typical Electrical Characteristics** (@ $T_A = +25^\circ\text{C}$ , unless otherwise specified.)



**Package Outline Dimensions**

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for the latest version.

**SOT223**

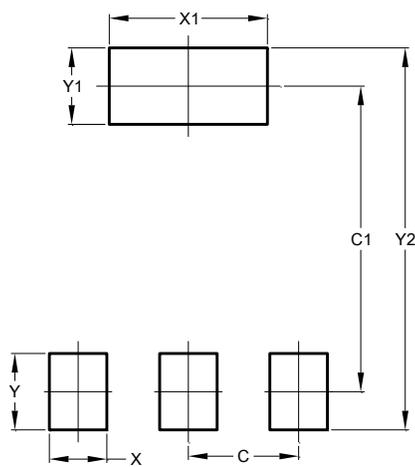


SOT223			
Dim	Min	Max	Typ
A	1.55	1.65	1.60
A1	0.010	0.15	0.05
b	0.60	0.80	0.70
b1	2.90	3.10	3.00
C	0.20	0.30	0.25
D	6.45	6.55	6.50
E	3.45	3.55	3.50
E1	6.90	7.10	7.00
e	-	-	4.60
e1	-	-	2.30
L	0.85	1.05	0.95
Q	0.84	0.94	0.89
All Dimensions in mm			

**Suggested Pad Layout**

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.

**SOT223**



Dimensions	Value (in mm)
C	2.30
C1	6.40
X	1.20
X1	3.30
Y	1.60
Y1	1.60
Y2	8.00

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